

CXT5551HC
SURFACE MOUNT
HIGH CURRENT
SILICON NPN TRANSISTOR



SOT-89 CASE

CentralTM
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CXT5551HC type is an high current NPN silicon transistor manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for high voltage and high current amplifier applications.

MARKING CODE: FULL PART NUMBER

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Collector Current
Power Dissipation
Operating and Storage
Junction Temperature
Thermal Resistance

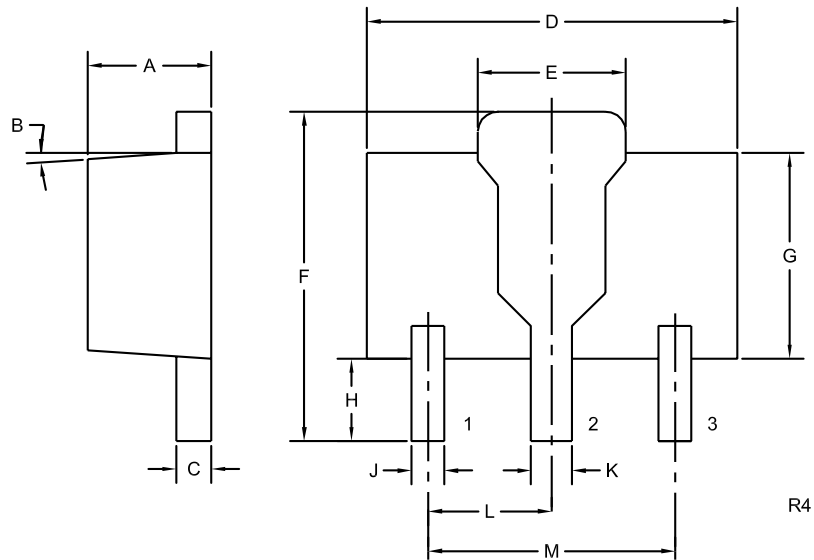
SYMBOL		UNITS
V_{CB0}	180	V
V_{CEO}	160	V
V_{EBO}	6.0	V
I_C	1.0	A
P_D	1.2	W
T_J, T_{stg}	-65 to +150	$^{\circ}\text{C}$
θ_{JA}	104	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{CBO}	$V_{CB}=120\text{V}$			50	nA
I_{CBO}	$V_{CB}=120\text{V}, T_A=100^{\circ}\text{C}$			50	μA
I_{EBO}	$V_{EB}=4.0\text{V}$			50	nA
BV_{CBO}	$I_C=100\mu\text{A}$	180			V
BV_{CEO}	$I_C=1.0\text{mA}$	160			V
BV_{EBO}	$I_E=10\mu\text{A}$	6.0			V
$V_{CE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$			0.15	V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$			0.20	V
$V_{BE(SAT)}$	$I_C=10\text{mA}, I_B=1.0\text{mA}$			1.00	V
$V_{BE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$			1.00	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	80			
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$	80		250	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=50\text{mA}$	30			
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{A}$		10		
f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	100			MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$			15	pF

R0 (28-January 2005)

SOT-89 CASE - MECHANICAL OUTLINE



BOTTOM VIEW

LEAD CODE:

- 1) EMITTER
- 2) COLLECTOR
- 3) BASE

MARKING CODE:

FULL PART NUMBER

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.055	0.067	1.40	1.70
B	4°		4°	
C	0.014	0.018	0.35	0.46
D	0.173	0.185	4.40	4.70
E	0.064	0.074	1.62	1.87
F	0.146	0.177	3.70	4.50
G	0.090	0.106	2.29	2.70
H	0.028	0.051	0.70	1.30
J	0.014	0.019	0.36	0.48
K	0.017	0.023	0.44	0.58
L	0.059		1.50	
M	0.118		3.00	

SOT-89 (REV: R4)